NSN 5961-01-069-3007

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Inclosure Material:

Ceramic and metal

Overall Length:

0.975 inches

Overall Height:

0.275 inches

Overall Width:

0.725 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

35.0 collector to emitter voltage/static/base open and 60.0 collector to emitter voltage, dc with base short-circuited to emitter and 4.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

1.00 amperes source cutoff current

Power Rating Per Characteristic:

20.0 watts small-signal input power, common-collector preset

Special Features:

Junction pattern arrangement: npn

Test Data Document:

87990-755002a7632 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0